OmniOn
POWER

40A Digital MegaDLynx™: Non-Isolated DC-DC Power Modules
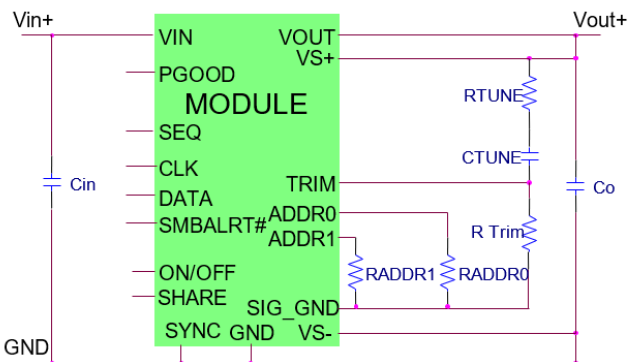
4.5V$_{dc}$ – 14.4V$_{dc}$ input; 0.45V$_{dc}$ to 2.0V$_{dc}$ output; 40A Output Current

RoHS Compliant

TUNABLE LOOP™

PMBus

Description

The 40A Digital Mega DLynx™ power modules are non-isolated dc-dc converters that can deliver up to 40A of output current. These modules operate over a wide range of input voltage (V$_{IN}$ = 4.5V$_{dc}$-14.4V$_{dc}$) and provide a precisely regulated output voltage from 0.45V$_{dc}$ to 2.0V$_{dc}$, programmable via an external resistor and PMBus control. Features include a digital interface using the PMBus protocol, remote On/Off, adjustable output voltage, over current and over temperature protection. The PMBus interface supports a range of commands to both control and monitor the module. The module also includes the Tunable Loop™ feature that allows the user to optimize the dynamic response of the converter to match the load with reduced amount of output capacitance leading to savings on cost and PWB area.

Applications

- Industrial equipment
- Distributed power architectures
- Intermediate bus voltage applications
- Telecommunications equipment
- Servers and storage applications
- Networking equipment

MDT040_DS   Rev. 1.9

Features

- Compliant to RoHS Directive 2011/65/EU and amended Directive (EU) 2015/863.

- Compliant to REACH Directive (EC) No 1907/2006

- Compliant to IPC-9592 (September 2008), Category 2, ClassII

- Compatible in a Pb-free or SnPb reflow environment (Z versions)

- Wide Input voltage range (4.5V_{dc}-14.4V_{dc})

- Output voltage programmable from 0.6V_{dc} to 2.0V_{dc} via external resistor. Digitally adjustable down to 0.45V_{dc}

- Digital interface through the PMBus™ # protocol

- Tunable Loop™ to optimize dynamic output voltage response

- Power Good signal

- Fixed switching frequency with capability of external synchronization

- Output overcurrent protection (non-latching)

- Over temperature protection

- Remote On/Off

- Ability to sink and source current

- Cost efficient open frame design

- Small size: 33.02 mm x 13.46 mm x 10.9 mm (1.3 in x 0.53 in x 0.429 in)

- Wide operating temperature range [-40°C to 105°C (Ruggedized: -D), 85°C(Regular).

- Ruggedized (-D) version able to withstand high levels of shock and vibration

- ANSI/UL* 62368-1 and CAN/CSA† C22.2 No. 62368-1 Recognized, DIN VDE‡ 0868-1/A11:2017 (EN62368-1:2014/A11:2017)

- ISO** 9001 and ISO 14001 certified manufacturing facilities

FOOTNOTES

* UL is a registered trademark of Underwriters Laboratories, Inc.

† CSA is a registered trademark of Canadian Standards Association.

‡ VDE is a trademark of Verband Deutscher Elektrotechniker e.V.

** ISO is a registered trademark of the International Organization of Standards

The PMBus name and logo are registered trademarks of the System Management Interface Forum (SMIF)

MDT040_DS Rev. 1.9

Technical Specifications

Absolute Maximum Ratings

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. These are absolute stress ratings only, functional operation of the device is not implied at these or any other conditions in excess of those given in the operations sections of the data sheet. Exposure to absolute maximum ratings for extended periods can adversely affect the device reliability.

Parameter	Device	Symbol	Min	Max	Unit
Input Voltage Continues	All	V_{IN}	-0.3	15	V
SEQ, SYNC, VS+	All			7	V
CLK, DATA, SMBALERT#	All			3.6	V
Operating Ambient Temperature (see Thermal Considerations section)	All	T_A	-40	105	°C
Storage Temperature	All	T_{stg}	-55	125	°C

Electrical Specifications

Unless otherwise indicated, specifications apply over all operating input voltage, resistive load, and temperature conditions.

Parameter	Device	Symbol	Min	Typ	Max	Unit
Operating Input Voltage	All	V_{IN}	4.5	-	14.4	V_{dc}
Maximum Input Current (V_{IN} = 4.5V to 14V, I_O =$I_{O, max}$)	All	$I_{IN,max}$			24	A_{dc}
Input No Load Current (V_{IN} = 12V_{dc}, I_O = 0, module enabled)	$V_{O, set}$ = 0.6 V_{dc}	$I_{IN,no\ load}$		54.7		mA
	$V_{O, set}$ = 2V_{dc}	$I_{IN\ no\ load}$		104		mA
Input Stand-by Current (V_{IN} = 12V_{dc}, module disabled)	All	$I_{IN, stand-by}$		12.5		mA
Inrush Transient	All	I^2t			1	A^2s
Input Reflected Ripple Current, peak-to-peak (5Hz to 20MHz, 1µH source impedance; V_{IN}=0 to 14V I_O= $I_{o\ max}$; see Test configuration section)	All			90		mA_{p-p}
Input Ripple Rejection (120Hz)	All			-60		dB
Output Voltage Set-point (with 0.1% tolerance for external resistor used to set output voltage)	All	$V_{O, set}$	-1.0		+1.0	%$V_{O, set}$
Output Voltage (Over all operating input voltage, resistive load, and temperature conditions until end of life)	All	$V_{O, set}$	-3.0		+3.0	%$V_{O, set}$
Adjustment Range (selected by an external resistor) (Some output voltages may not be possible depending on the input voltage – see Feature Descriptions Section)	All	V_O	0.6		2.0	V_{dc}
PMBus Adjustable Output Voltage Range	All	$V_{O,adj}$	-25	0	+25	%$V_{O, set}$
PMBus Output Voltage Adjustment Step Size	All			0.4		%$V_{O, set}$

MDT040_DS Rev. 1.9

Technical Specifications (continued)

Electrical Specifications (continued)

Parameter	Device	Symbol	Min	Typ	Max	Unit
Remote Sense Range	All				0.5	V_{dc}
Output Regulation						
Line ($V_{IN}=V_{IN, min}$ to $V_{IN, max}$)	All			-	6	mV
Load ($I_O=I_{O, min}$ to $I_{O, max}$)	All			-	10	mV
Temperature ($T_{ref}=T_{A, min}$ to $T_{A, max}$)	All			0.4		$\%V_{O, set}$
Output Ripple and Noise on nominal output						
($V_{IN}=V_{IN, nom}$ and $I_O=I_{O, min}$ to $I_{O, max}$ $C_o = 0.1\mu F // 22\ \mu F$ ceramic capacitors)						
Peak-to-Peak (5MHz to 20MHz bandwidth)	All		-	50	100	$mV_{pk\text{-}pk}$
RMS (5MHz to 20MHz bandwidth)	All			20	38	mV_{rms}
External Capacitance[1] Without the Tunable Loop™						
ESR ≥ 1 mΩ	All	$C_{O, max}$	6x47	-	6x47	µF
With the Tunable Loop™						
ESR ≥ 0.15 mΩ	All	$C_{O, max}$	6x47	-	7000	µF
ESR ≥ 10 mΩ	All	$C_{O, max}$	6x47	-	8500	µF
Output Current (in either sink or source mode)	All	I_o	0		40	A_{dc}
Output Current Limit Inception (Hiccup Mode) (current limit does not operate in sink mode)	All	$I_{O, lim}$		150	180	$\% I_{o,max}$
Output Short-Circuit Current ($V_O ≤ 250mV$) (Hiccup Mode)	All	$I_{O, s/c}$		2.1	2.83	A_{rms}
Efficiency	$V_{O, set} = 0.6\ V_{dc}$	η	78.0	81.3		%
$V_{IN}= 12V_{dc}$, $T_A=25°C$	$V_{O, set} = 1.2\ V_{dc}$	η	84.0	88.5		%
$I_O=I_{O, max}$, $V_O= V_{O,set}$	$V_{O, set} = 1.8\ V_{dc}$	η	85.25	91.5		%
Switching Frequency	All	f_{sw}	380	400	420	kHz
Frequency Synchronization	All					
Synchronization Frequency Range	All		350		480	kHz
High-Level Input Voltage	All	V_{IH}	2.0			V
Low-Level Input Voltage	All	V_{IL}			0.4	V
Input Current, SYNC	All	I_{SYNC}			100	nA
Minimum Pulse Width, SYNC	All	t_{SYNC}	100			ns
Maximum SYNC rise time	All	t_{SYNC_SH}	100			ns

[1] External capacitors may require using the new Tunable Loop™ feature to ensure that the module is stable as well as getting the best transient response. See the Tunable Loop™ section for details.

General Specifications

Parameter	Device	Min	Typ	Max	Unit
Calculated MTBF ($I_O=0.8\ I_{O, max}$, $T_A=40°C$) Telcordia Issue 2	All		6,498,438		Hours
Weight		10.53 (0.37)	11.7 (0.41)	12.87 (0.45)	g (oz.)

MDT040_DS
Rev. 1.9

Technical Specifications (continued)

Feature Specifications

Unless otherwise indicated, specifications apply over all operating input voltage, resistive load, and temperature conditions. See Feature Descriptions for additional information.

Parameter	Device	Symbol	Min	Typ	Max	Unit
On/Off Signal Interface ($V_{IN}=V_{IN, min}$ to $V_{IN, max}$; open collector or equivalent, Signal referenced to GND)						
Device Code with no suffix "4"– Positive Logic (See Ordering Information)						
Logic High (Module ON)						
Input High Current	All	I_{IH}		-	10	µA
Input High Voltage	All	V_{IH}	3.5	-	$V_{IN,max}$	V
Logic Low (Module OFF)						
Input Low Current	All	I_{IL}	-	-	1	mA
Input Low Voltage	All	V_{IL}	-0.3	-	0.4	V
Device Code with no suffix – Negative Logic (See Ordering Information)						
(On/OFF pin is open collector/drain logic input with external pull-up resistor; signal referenced to GND)						
Logic High (Module OFF)						
Input High Current	All	I_{IH}	-	-	1	mA
Input High Voltage	All	V_{IH}	2	-	$V_{IN,max}$	V_{dc}
Logic Low (Module ON)						
Input low Current	All	I_{IL}	-	-	10	µA
Input Low Voltage	All	V_{IL}	-0.2	-	0.4	V_{dc}
Turn-On Delay and Rise Times						
($V_{IN}=V_{IN, nom}$, $I_O=I_{O, max}$, V_O to within ±1% of steady state) Case 1: On/Off input is enabled and then input power is applied (delay from instant at which $V_{IN} = V_{IN ,min}$ until V_o =10% of $V_{o, set}$)	All	T_{delay}	1.0	1.1	1.7	msec
Case 2: Input power is applied for at least one second and then the On/Off input is enabled (delay from instant at which $V_{on/Off}$ is enabled until V_o = 10% of $V_{o, set}$)	All	T_{delay}	600	700	1800	µsec
Output voltage Rise time (time for V_o to rise from 10% of $V_{o, set}$ to 90% of $V_{o, set}$)	All	T_{rise}	1.2	1.5	2.2	msec
Output voltage overshoot (T_A = 25°C $V_{IN}= V_{IN, min}$ to $V_{IN, max}$, $I_O = I_{O, min}$ to $I_{O, max}$) With or without maximum external capacitance			0	1.5	3.0	% $V_{O, set}$
Over Temperature Protection (See Thermal Considerations section)	All	T_{ref}	123	130	137	°C
PMBus Over Temperature Warning Threshold*	All	T_{WARN}	120	130	140	°C
Tracking Accuracy ($V_{IN, min}$ to $V_{IN, max}$; $I_{O, min}$ to $I_{O, max}$ $V_{SEQ} < V_o$)						
(Power-Up: 0.5V/ms)	All	$V_{SEQ} – V_o$			100	mV
(Power-Down: 0.5V/ms)	All	$V_{SEQ} – V_o$			100	mV
Input Undervoltage Lockout						
Turn-on Threshold	All		4.144	4.25	4.407	V_{dc}
Turn-off Threshold	All		3.947	3.98	4.163	V_{dc}
Hysteresis	All		0.25	0.3	0.35	V_{dc}
PMBus Adjustable Input Under Voltage Lockout Thresholds	All		2.5		14	V_{dc}
Resolution of Adjustable Input Under Voltage Threshold	All				500	mV

* Over temperature Warning – Warning may not activate before alarm and unit may shutdown before warning

MDT040_DS   Rev. 1.9

Technical Specifications (continued)

Feature Specifications (continued)

Parameter	Device	Symbol	Min	Typ	Max	Unit
PGOOD (Power Good)						
Signal Interface Open Drain, $V_{supply} \leq 5V_{DC}$						
Overvoltage threshold for PGOOD ON	All		103	108	113	% $V_{O, set}$
Overvoltage threshold for PGOOD OFF	All		105	110	115	% $V_{O, set}$
Undervoltage threshold for PGOOD ON	All		87	92	97	% $V_{O, set}$
Undervoltage threshold for PGOOD OFF	All		85	90	95	% $V_{O, set}$
Pulldown resistance of PGOOD pin	All				50	Ω
Sink current capability into PGOOD pin	All				5	mA

Digital Interface Specifications

Unless otherwise indicated, specifications apply over all operating input voltage, resistive load, and temperature conditions. See Feature Descriptions for additional information.

Parameter	Conditions	Symbol	Min	Typ	Max	Unit
PMBus Signal Interface Characteristics						
Input High Voltage (CLK, DATA)		V_{IH}	2.1		3.6	V
Input Low Voltage (CLK, DATA)		V_{IL}			0.8	V
Input high level current (CLK, DATA)		I_{IH}	-10		10	µA
Input low level current (CLK, DATA)		I_{IL}	-10		10	µA
Output Low Voltage (CLK, DATA, SMBALERT#)	I_{OUT}=2mA	V_{OL}			0.4	V
Output high level open drain leakage current (DATA, SMBALERT#)	V_{OUT}=3.6V	I_{OH}	0		10	µA
Pin capacitance		C_o		0.7		pF
PMBus Operating frequency range	Slave Mode	F_{PMB}	10		400	kHz
Data hold time	Receive Mode	$t_{HD:DAT}$	0			ns
	Transmit Mode		300			
Data setup time		$t_{SU:DAT}$	250			ns
Measurement System Characteristics						
Read delay time		t_{DLY}	153	192	231	µs
Output current measurement range		I_{RNG}	0		40	A
Output current measurement resolution		I_{RES}	62.5			mA
Output current measurement accuracy at 25°C		I_{ACC}			±5	%
Output current measurement offset		I_{OFST}			0.1	A
V_{OUT} measurement range		$V_{OUT(rng)}$	0		2.0	V
V_{OUT} measurement resolution		$V_{OUT(res)}$		16.25		mV
V_{OUT} measurement gain accuracy		$V_{OUT(gain)}$	-2		2	LSB
V_{OUT} measurement offset		$V_{OUT(ofst)}$	-3		3	%
V_{OUT} measurement gain accuracy		$V_{OUT, (ACC)}$	-15		+15	%
V_{IN} measurement range		$V_{IN(rng)}$	0		14.4	V
V_{IN} measurement resolution		$V_{IN(res)}$		32.5		mV
V_{IN} measurement gain accuracy		$V_{IN(gain)}$	-2		2	LSB
V_{IN} measurement offset		$V_{IN(ofst)}$	-5.5		1.4	%
V_{IN} measurement accuracy		V_{IN}	-3		+3	%

MDT040_DS   Rev. 1.9

Technical Specifications (continued)

Characteristic Curves

The following figures provide typical characteristics for the 40A Digital Mega DLynx™ at 0.6V$_o$ and 25°C.

Figure 1. Converter Efficiency versus Output Current.

Figure 2. Derating Output Current versus Ambient Temperature and Airflow.

Figure 3. Typical output ripple and noise (C_O=6x47µF ceramic, V_{IN} = 12V, $I_o = I_{o,max}$).

Figure 4. Transient Response to Dynamic Load Change from 50% to 100% at 12V$_{in}$, C$_{out}$= 12x680uF +6x47uF C$_{Tune}$=47nF, R$_{Tune}$=180 ohms

Figure 5. Typical Start-up Using On/Off Voltage ($I_o = I_{o,max}$).

Figure 6. Typical Start-up Using Input Voltage (V_{IN} = 12V, $I_o = I_{o,max}$).

MDT040_DS   Rev. 1.9

Characteristic Curves (continued)

The following figures provide typical characteristics for the 40A Digital Mega DLynx™ at 1.2V$_o$ and 25°C.

Figure 7. Converter Efficiency versus Output Current.

Figure 8. Derating Output Current versus Ambient Temperature and Airflow.

Figure 9. Typical output ripple and noise (C$_O$=6x47μF ceramic, V$_{IN}$ = 12V, I$_o$ = I$_{o,max}$).

Figure 10. Transient Response to Dynamic Load Change from 50% to 100% at 12V$_{in}$, C$_{out}$= 6x330uF, C$_{Tune}$=12nF, R$_{Tune}$=200 ohms

Figure 11. Typical Start-up Using On/Off Voltage (I$_o$ = I$_{o,max}$).

Figure 12. Typical Start-up Using Input Voltage (V$_{IN}$ = 12V, I$_o$ = I$_{o,max}$).

MDT040_DS   Rev. 1.9

Characteristic Curves (continued)

The following figures provide typical characteristics for the 40A Digital Mega DLynx™ at 1.8V$_o$ and 25°C.

Figure 13 Converter Efficiency versus Output Current.

Figure 14. Derating Output Current versus Ambient Temperature and Airflow.

Figure 15. Typical output ripple and noise (C$_O$=6x47µF ceramic, V$_{IN}$ = 12V, I$_o$ = I$_{o,max}$).

Figure 16. Transient Response to Dynamic Load Change from 50% to 100% at 12V$_{in}$, C$_{out}$= 6x330uF, C$_{Tune}$=5.6nF, R$_{Tune}$=220 ohms

Figure 17. Typical Start-up Using On/Off Voltage (I$_o$ = I$_{o,max}$).

Figure 18. Typical Start-up Using Input Voltage (V$_{IN}$ = 12V, I$_o$ = I$_{o,max}$).

MDT040_DS
Rev. 1.9

Technical Specifications (continued)

Design Considerations

Input Filtering

The 40A Digital Mega DLynx™ module should be connected to a low ac-impedance source. A highly inductive source can affect the stability of the module. An input capacitance must be placed directly adjacent to the input pin of the module, to minimize input ripple voltage and ensure module stability.

To minimize input voltage ripple, ceramic capacitors are recommended at the input of the module. Figure 19 shows the input ripple voltage for various output voltages at 40A of load current with 4x22 μF, 6x22μF or 8x22uF ceramic capacitors and an input of 12V.

Figure 19. Input ripple voltage for various output voltages with various external ceramic capacitors at the input (40A load). Input voltage is 12V. Scope Bandwidth limited to 20MHz

Output Filtering

These modules are designed for low output ripple voltage and will meet the maximum output ripple specification with 0.1 μF ceramic and 47 μF ceramic capacitors at the output of the module. However, additional output filtering may be required by the system designer for a number of reasons. First, there may be a need to further reduce the output ripple and noise of the module. Second, the dynamic response characteristics may need to be customized to a particular load step change.

To reduce the output ripple and improve the dynamic response to a step load change, additional capacitance at the output can be used. Low ESR polymer and ceramic capacitors are recommended to improve the dynamic response of the module. Figure 20 provides output ripple information for different external capacitance values at various Vo and a full

load current of 40A. For stable operation of the module, limit the capacitance to less than the maximum output capacitance as specified in the electrical specification table. Optimal performance of the module can be achieved by using the Tunable Loop™ feature described later in this data sheet.

Figure 20. Output ripple voltage for various output voltages with external 6x47 μF, 8x47 μF or 10x47 μF ceramic capacitors at the output (40A load). Input voltage is 12V. Scope Bandwidth limited to 20MHz

Safety Considerations

For safety agency approval the power module must be installed in compliance with the spacing and separation requirements of the end-use safety agency standards, i.e., UL ANSI/UL* 62368-1 and CAN/CSA+ C22.2 No. 62368-1 Recognized, DIN VDE 0868-1/A11:2017 (EN62368- 1:2014/A11:2017.

For the converter output to be considered meeting the Requirements of safety extra-low voltage (SELV) or ES1, the input must meet SELV/ES1 requirements. The power module has extra-low voltage (ELV) outputs when all inputs are ELV. The input to these units is to be provided with a fast acting fuse with a maximum rating of 30A, 100V (for example, Little fuse 456 series) in the positive input lead.

MDT040_DS   Rev. 1.9

Technical Specifications (continued)

Analog Feature Descriptions

Remote On/Off

The module can be turned ON and OFF either by using the ON/OFF pin (Analog interface) or through the PMBus interface (Digital). The module can be configured in a number of ways through the PMBus interface to react to the two ON/OFF inputs:

- Module ON/OFF can be controlled only through the analog interface (digital interface ON/OFF commands are ignored)

- Module ON/OFF can be controlled only through the PMBus interface (analog interface is ignored)

- Module ON/OFF can be controlled by either the analog or digital interface

The default state of the module (as shipped from the factory) is to be controlled by the analog interface only. If the digital interface is to be enabled, or the module is to be controlled only through the digital interface, this change must be made through the PMBus. These changes can be made and written to non-volatile memory on the module so that it is remembered for subsequent use.

Analog On/Off

The 40A Digital Mega DLynx™ power modules feature an On/Off pin for remote On/Off operation. Two On/Off logic options are available. In the Positive Logic On/Off option, (device code suffix "4" – see Ordering Information), the module turns ON during a logic High on the On/Off pin and turns OFF during a logic Low. With the Negative Logic On/Off option, (no device code suffix, see Ordering Information), the module turns OFF during logic High and ON during logic Low. The On/Off signal should be always referenced to ground. For either On/Off logic option, leaving the On/Off pin disconnected will turn the module ON when input voltage is present.

For positive logic modules, the circuit configuration for using the On/Off pin is shown in Figure 21.

For negative logic On/Off modules, the circuit configuration is shown in Fig. 22.

Figure 21. Circuit configuration for using positive On/Off logic.

Figure 22. Circuit configuration for using negative On/Off logic.

Digital On/Off

Please see the Digital Feature Descriptions section.

Monotonic Start-up and Shutdown

The module has monotonic start-up and shutdown behavior for any combination of rated input voltage, output current and operating temperature range.

Startup into Pre-biased Output

The module can start into a pre-biased output as long as the pre-bias voltage is 0.5V less than the set output voltage.

MDT040_DS   Rev. 1.9

Technical Specifications (continued)

Analog Feature Descriptions (continued)

Analog Output Voltage Programming

The output voltage of the module is programmable to any voltage from 0.6dc to 2.0V_{dc} by connecting a resistor between the Trim and SIG_GND pins of the module. Certain restrictions apply on the output voltage set point depending on the input voltage. These are shown in the Output Voltage vs. Input Voltage Set Point Area plot in Fig. 23. The Upper Limit curve shows that for output voltages lower than 1V, the input voltage must be lower than the maximum of 14.4V. The Lower Limit curve shows that for output voltages higher than 0.6V, the input voltage needs to be larger than the minimum of 4.5V.

Figure 23. Output Voltage vs. Input Voltage Set Point Area plot showing limits where the output voltage can be set for different input voltages.

Figure 24. Circuit configuration for programming output voltage using an external resistor.

Caution – Do not connect SIG_GND to GND elsewhere in the layout

Without an external resistor between Trim and SIG_GND pins, the output of the module will be 0.6V_{dc}. To calculate the value of the trim resistor, R_{trim} for a desired output voltage, should be as per the following equation:

$$R_{trim} = \left[\frac{12}{V_o - 0.6} \right] \ k\Omega$$

R_{trim} is the external resistor in kΩ

V_o is the desired output voltage.

Table 1 provides R_{trim} values required for some common output voltages.

$V_{O, set}$ (V)	R_{trim} (KΩ)
0.6	Open
0.9	40
1.0	30
1.2	20
1.5	13.33
1.8	10

Table 1

Digital Output Voltage Adjustment

Please see the Digital Feature Descriptions section.

Remote Sense

The power module has a Remote Sense feature to minimize the effects of distribution losses by regulating the voltage between the sense pins (VS+ and VS-). The voltage drop between the sense pins and the V_{OUT} and GND pins of the module should not exceed 0.5V.

Analog Voltage Margining

Output voltage margining can be implementeda in the module by connecting a resistor, $R_{margin-up}$, from the Trim pin to the ground pin for margining-up the output voltage and by connecting a resistor, $R_{margin-down}$, from the Trim pin to output pin for margining-down. Figure 25 shows the circuit configuration for output voltage margining. The POL

Programming Tool, available at **omnionpower.com** under the Downloads section, also calculates the values of $R_{margin-up}$ and $R_{margin-down}$ for a specific output voltage and % margin. Please consult your local OmniOn technical representative for additional details.

MDT040_DS   Rev. 1.9

Analog Feature Descriptions (continued)

Analog Voltage Margining (continued)

Figure 25. Circuit Configuration for margining Output voltage.

Digital Output Voltage Margining

Please see the Digital Feature Descriptions section.

Output Voltage Sequencing

The power module includes a sequencing feature, EZSEQUENCE that enables users to implement various types of output voltage sequencing in their applications. This is accomplished via an additional sequencing pin. When not using the sequencing feature, leave it unconnected.

The voltage applied to the SEQ pin should be scaled down by the same ratio as used to scale the output voltage down to the reference voltage of the module. This is accomplished by an external resistive divider connected across the sequencing voltage before it is fed to the SEQ pin as shown in Fig. 26. In addition, a small capacitor (suggested value 100pF) should be connected across the lower resistor R1.

For all DLynx modules, the minimum recommended delay between the ON/OFF signal and the sequencing signal is 10ms to ensure that the module output is ramped up according to the sequencing signal. This ensures that the module soft-start routine is completed before the sequencing signal is allowed to ramp up.

Figure 26. Circuit showing connection of the sequencing signal to the SEQ pin.

When the scaled down sequencing voltage is applied to the SEQ pin, the output voltage tracks this voltage until the output reaches the set-point voltage. The final value of the sequencing voltage must be set higher than the set-point voltage of the module. The output voltage follows the sequencing voltage on a one-to-one basis. By connecting multiple modules together, multiple modules can track their output voltages to the voltage applied on the SEQ pin.

The module's output can track the SEQ pin signal with slopes of up to 0.5V/msec during power-up or power-down.

To initiate simultaneous shutdown of the modules, the SEQ pin voltage is lowered in a controlled manner. The output voltage of the modules tracks the voltages below their set-point voltages on a one-to-one basis. A valid input voltage must be maintained until the tracking and output voltages reach ground potential.

Note that in all digital DLynx series of modules, the PMBus Output Undervoltage Fault will be tripped when sequencing is employed. This will be detected using the STATUS_WORD and STATUS_VOUT PMBus commands. In addition, the SMBALERT# signal will be asserted low as occurs for all faults and warnings. To avoid the module shutting down due to the Output Undervoltage Fault, the module must be set to continue operation without interruption as the response to this fault (see the description of the PMBus command VOUT_UV_FAULT_RESPONSE for additional information).

MDT040_DS   Rev. 1.9

Analog Feature Descriptions (continued)

Overcurrent Protection

To provide protection in a fault (output overload) condition, the unit is equipped with internal current-limiting circuitry and can endure current limiting continuously. At the point of current-limit inception, the unit enters hiccup mode. The unit operates normally once the output current is brought back into its specified range.

Load Transient Considerations

The MDT040 module can achieve 100% load transient above 0°C ambient temperature. Below 0°C ambient temperature, the load transient is limited to a maximum of 62.5% of specified full load current.

Digital Adjustable Overcurrent Warning

Please see the Digital Feature Descriptions section.

Overtemperature Protection

To provide protection in a fault condition, the unit is equipped with a thermal shutdown circuit. The unit will shut down if the over temperature threshold of 145°C(typ) is exceeded at the thermal reference point T_{ref} .Once the unit goes into thermal shutdown it will then wait to cool before attempting to restart.

Digital Temperature Status via PMBus

Please see the Digital Feature Descriptions section.

Digitally Adjustable Output Over and Under Voltage Protection

Please see the Digital Feature Descriptions section.

Input Undervoltage Lockout

At input voltages below the input undervoltage lockout limit, the module operation is disabled. The module will begin to operate at an input voltage above the undervoltage lockout turn-on threshold.

Digitally Adjustable Input Undervoltage Lockout

Please see the Digital Feature Descriptions section.

Digitally Adjustable Power Good Thresholds

Please see the Digital Feature Descriptions section.

Synchronization

The module switching frequency can be synchronized to a signal with an external frequency within a specified range. Synchronization can be done by using the external signal applied to the SYNC pin of the module as shown in Fig. 27, with the converter being synchronized by the rising edge of the external signal.

The Electrical Specifications table specifies the requirements of the external SYNC signal. If the SYNC pin is not used, the module should free run at the default switching frequency. If synchronization is not being used, connect the SYNC pin to GND.

Figure 27. External source connections to synchronize switching frequency of the module.

Paralleling with Active Load Sharing (-P Option)

For additional power requirements, the Mega DLynx™ power module is also equipped with paralleling capability. Up to five modules can be configured in parallel, with active load sharing.

To implement paralleling, the following conditions must be satisfied.

- All modules connected in parallel must be frequency synchronized where they are switching at the same frequency. This is done by using the SYNC function of the module and connecting to an external frequency source. Modules can be interleaved to reduce input ripple/filtering requirements.

- The share pins of all units in parallel must be connected together. The path of these connections should be as direct as possible.

- The remote sense connections to all modules should be made that to same points for the output, i.e. all VS+ and VS- terminals for all modules are connected to the power bus at the same points.

- For converters operating in parallel, tunable loop components "R_{TUNE}" and "C_{TUNE}" must be selected to meet the required transient specification. For providing better noise immunity, we recommend that RTUNE value to be greater than 300Ω.

Some special considerations apply for design of converters in parallel operation:

- When sizing the number of modules required for parallel operation, take note of the fact that current sharing has some tolerance. In addition, under transient conditions such as a dynamic load

Analog Feature Descriptions (continued)

Paralleling with Active Load Sharing (-P Option) (continued)

change and during startup, all converter output currents will not be equal. To allow for such variation and avoid the likelihood of a converter shutting off due to a current overload, the total capacity of the paralleled system should be no more than 90% of the sum of the individual converters. As an example, for a system of three MegaDLynx™ converters in parallel, the total current drawn should be less that 90% of (3 x 40A), i.e. less than 108 A. Similarly, four units can support a load less than 144 A.

- All modules should be turned ON and OFF together. This is so that all modules come up at the same time avoiding the problem of one converter sourcing current into the other leading to an overcurrent trip condition. To ensure that all modules come up simultaneously, the on/off pins of all paralleled converters should be tied together and the converters enabled and disabled using the on/off pin. Note that this means that converters in parallel cannot be digitally turned ON as that does not ensure that all modules being paralleled turn on at the same time.

- If digital trimming is used to adjust the overall output voltage, the adjustments need to be made in a series of small steps to avoid shutting down the output. Each step should be no more than 20mV for each module. For example, to adjust the overall output voltage in a setup with two modules (A and B) in parallel from 1V to 1.1V, module A would be adjusted from 1.0 to 1.02V followed by module B from 1.0 to 1.02V, then each module in sequence from 1.02 to 1.04V and so on until the final output voltage of 1.1V is reached.

- If the Sequencing function is being used to start-up and shut down modules and the module is being held to 0V by the tracking signal then there may be small deviations on the module output. This is due to controller duty cycle limitations encountered in trying to hold the voltage down near 0V.

- The share bus is not designed for redundant operation and the system will be non-functional upon failure of one of the units when multiple units are in parallel. In particular, if one of the converters shuts down during operation, the other converters may also shut down due to their outputs hitting current limit. In such a situation, unless a coordinated restart is ensured, the system may never properly restart since different converters will try to restart at different times causing an overload condition and subsequent shutdown. This situation can be avoided by having an external output voltage monitor circuit that detects a shutdown condition and forces all converters to shut down and restart together.

When not using the active load share feature, share pins should be left unconnected.

Measuring Output Current, Output Voltage and Input Voltage

Please see the Digital Feature Descriptions section.

Dual Layout

Identical dimensions and pin layout of Analog and Digital Mega DLynx modules permit migration from one to the other without needing to change the layout. In both cases the trim resistor is connected between trim and signal ground.

Tunable Loop™

The module has a feature that optimizes transient response of the module called Tunable Loop™.

External capacitors are usually added to the output of the module for two reasons: to reduce output ripple and noise (see Figure 38) and to reduce output voltage deviations from the steady-state value in the presence of dynamic load current changes. Adding external capacitance however affects the voltage control loop of the module, typically causing the loop to slow down with sluggish response. Larger values of external capacitance could also cause the module to become unstable.

The Tunable Loop™ allows the user to externally adjust the voltage control loop to match the filter network connected to the output of the module. The Tunable Loop™ is implemented by connecting a series R-C between the VS+ and TRIM pins of the module, as shown in Fig. 28. This R-C allows the user to externally adjust the voltage loop feedback compensation of the module.

Figure. 28. Circuit diagram showing connection of R_{TUNE} and C_{TUNE} to tune the control loop of the module.

MDT040_DS   Rev. 1.9

Technical Specifications (continued)

Analog Feature Descriptions (continued)

Tunable Loop™ (continued)

Recommended values of R_{TUNE} and C_{TUNE} for different output capacitor combinations are given in Table 2. Table 2 shows the recommended values of R_{TUNE} and C_{TUNE} for different values of ceramic output capacitors up to 1000uF that might be needed for an application to meet output ripple and noise requirements. Selecting R_{TUNE} and C_{TUNE} according to Table 2 will ensure stable operation of the module.

In applications with tight output voltage limits in the presence of dynamic current loading, additional output capacitance will be required. Table 3 lists recommended values of R_{TUNE} and C_{TUNE} in order to meet 2% output voltage deviation limits for some common output voltages in the presence of a 20A to 40A step change (50% of full load), with an input voltage of 12V.

Please contact your OmniOn technical representative to obtain more details of this feature as well as for guidelines on how to select the right value of external R-C to tune the module for best transient performance and stable operation for other output capacitance values.

C_O	6x47µF	8x47µF	10x47µF	12x47µF	20x47µF
R_{TUNE}	330Ω	330Ω	330Ω	330Ω	200Ω
C_{TUNE}	330pF	820pF	1200pF	1500pF	3300pF

Table 2. General recommended values of of R_{TUNE} and C_{TUNE} for V_{in}=12V and various external ceramic capacitor combinations.

V_O	1.8V	1.2V	0.6V
C_O	4x47uF + 6x330µF polymer	4x47uF + 11x330µF polymer	4x47uF + 12x680µF polymer
R_{TUNE}	220 Ω	200 Ω	180 Ω
C_{TUNE}	5600pF	12nF	47nF
ΔV	34mV	22mV	12mV

Table 3. Recommended values of R_{TUNE} and C_{TUNE} to obtain transient deviation of 2% of V_{out} for a 20A step load with V_{in}=12V.

Note: The capacitors used in the Tunable Loop tables are 47 µF/3 mΩ ESR ceramic, 330 µF/12 mΩ ESR polymer capacitor and 680µF/12 mΩ polymer capacitor.

Digital Feature Descriptions

PMBus Interface Capability

The 40A Digital Mega DLynx™ power modules have a PMBus interface that supports both communication and control. The PMBus Power Management Protocol Specification can be obtained from www.pmbus.org. The modules support a subset of version 1.1 of the specification (see Table 6 for a list of the specific commands supported). Most module parameters can be programmed using PMBus and stored as defaults for later use.

All communication over the module PMBus interface must support the Packet Error Checking (PEC) scheme. The PMBus master must generate the correct PEC byte for all transactions, and check the PEC byte returned by the module.

The module also supports the SMBALERT# response protocol whereby the module can alert the bus master if it wants to talk. For more information on the SMBus alert response protocol, see the System Management Bus (SMBus) specification.

The module has non-volatile memory that is used to store configuration settings. Not all settings programmed into the device are automatically saved into this non-volatile memory, only those specifically identified as capable of being stored can be saved (see Table 6 for which command parameters can be saved to non-volatile storage).

PMBus Data Format

For commands that set thresholds, voltages or report such quantities, the module supports the "Linear" data format among the three data formats supported by PMBus. The Linear Data Format is a two byte value with an 11-bit, two's complement mantissa and a 5-bit, two's complement exponent. The format of the two data bytes is shown below:

The value is of the number is then given by

$$Value = Mantissa \times 2^{Exponent}$$

MDT040_DS   Rev. 1.9

Technical Specifications (continued)

Digital Feature Descriptions (continued)

PMBus Addressing

The power module can be addressed through the PMBus using a device address. The module has 64 possible addresses (0 to 63 in decimal) which can be set using resistors connected from the ADDR0 and ADDR1 pins to SIG_GND. Note that some of these addresses (0, 1, 2, 3, 4, 5, 6, 7, 8, 9, 10, 11 12, 40, 44, 45, 55 in decimal) are reserved according to the SMBus specifications and may not be useable. The address is set in the form of two octal (0 to 7) digits, with each pin setting one digit. The ADDR1 pin sets the high order digit and ADDR0 sets the low order digit. The resistor values suggested for each digit are shown in Table 4 (1% tolerance resistors are recommended). Note that if either address resistor value is outside the range specified in Table 4, the module will respond to address 127.

Digit	Resistor Value (KΩ)
0	10
1	15.4
2	23.7
3	36.5
4	54.9
5	84.5
6	130
7	200

Table 4

The user must know which I²C addresses are reserved in a system for special functions and set the address of the module to avoid interfering with other system operations. Both 100kHz and 400kHz bus speeds are supported by the module. Connection for the PMBus interface should follow the High Power DC specifications given in section 3.1.3 in the SMBus specification V2.0 for the 400kHz bus speed or the Low Power DC specifications in section 3.1.2. The complete SMBus specification is available from the SMBus web site, smbus.org.

Figure 29. Circuit showing connection of resistors used to set the PMBus address of the module.

PMBus Enabled On/Off

The module can also be turned on and off via the PMBus interface. The OPERATION command is used to actually turn the module on and off via the PMBus, while the ON_OFF_CONFIG command configures the combination of analog ON/OFF pin input and PMBus commands needed to turn the module on and off. Bit [7] in the OPERATION command data byte enables the module, with the following functions:

> 0 : Output is disabled
>
> 1 : Output is enabled

This module uses the lower five bits of the ON_OFF_CONFIG data byte to set various ON/OFF options as follows:

Bit Position	4	3	2	1	0
Access	r/w	r/w	r/w	r/w	r
Function	PU	CMD	CPR	POL	CPA
Default Value	1	0	1	1	1

PU: Sets the default to either operate any time input power is present or for the ON/OFF to be controlled by the analog ON/OFF input and the PMBus OPERATION command. This bit is used together with the CP, CMD and ON bits to determine startup.

Bit Value	Action
0	Module powers up any time power is present regardless of state of the analog ON/OFF pin
1	Module does not power up until commanded by the analog ON/OFF pin and the OPERATION command as programmed in bits [2:0] of the ON_OFF_CONFIG register.

CMD: The CMD bit controls how the device responds to the OPERATION command.

Bit Value	Action
0	Module ignores the ON bit in the OPERATION command
1	Module responds to the ON bit in the OPERATION command

CPR: Sets the response of the analog ON/OFF pin. This bit is used together with the CMD, PU and ON bits to determine startup.

Bit Value	Action
0	Module ignores the analog ON/OFF pin, i.e.ON/OFF is only controlled through the PMBUS via the OPERATION command
1	Module requires the analog ON/OFF pin to be asserted to start the unit

Digital Feature Descriptions (continued)

PMBus Adjustable Soft Start Rise Time (continued)

The soft start rise time can be adjusted in the module via PMBus. When setting this parameter, make sure that the charging current for output capacitors can be delivered by the module in addition to any load current to avoid nuisance tripping of the overcurrent protection circuitry during startup. The TON_RISE command sets the rise time in ms, and allows choosing soft start times between 600μs and 9ms, with possible values listed in Table 5. Note that the exponent is fixed at -4 (decimal) and the upper two bits of the mantissa are also fixed at 0.

Rise Time	Exponent	Mantissa
600μs	11100	00000001010
900μs	11100	00000001110
1.2ms	11100	00000010011
1.8ms	11100	00000011101
2.7ms	11100	00000101011
4.2ms	11100	00001000011
6.0ms	11100	00001100000
9.0ms	11100	00010010000

Table 5

Output Voltage Adjustment Using the PMBus

The VOUT_SCALE_LOOP parameter is important for a number of PMBus commands related to output voltage trimming, margining, over/under voltage protection and the PGOOD thresholds. The output voltage of the module is set as the combination of the voltage divider formed by R_{Trim} and a 20kΩ upper divider resistor inside the module, and the internal reference voltage of the module. The reference voltage VREF is nominally set at 600mV, and the output regulation voltage is then given by

$$V_{OUT} = \left[\frac{20000 + R_{Trim}}{R_{Trim}} \right] \times V_{REF}$$

Hence the module output voltage is dependent on the value of R_{Trim} which is connected external to the module. The information on the output voltage divider ratio is conveyed to the module through the VOUT_SCALE_LOOP parameter which is calculated as follows:

$$VOUT\_SCALE\_LOOP = \frac{R_{Trim}}{20000 + R_{Trim}}$$

The VOUT_SCALE_LOOP parameter is specified using the "Linear" format and two bytes. The upper five bits [7:3] of the high byte are used to set the exponent which is fixed at –9 (decimal). The remaining three bits of the high byte [2:0] and the eight bits of the lower byte are used for the mantissa. The default value of the mantissa is 00100000000 corresponding to 256 (decimal), corresponding to a divider ratio of 0.5. The maximum value of the mantissa is 512 corresponding to a divider ratio of 1. Note that the resolution of the VOUT_SCALE_LOOP command is 0.2%.

When PMBus commands are used to trim or margin the output voltage, the value of VREF is what is changed inside the module, which in turn changes the regulated output voltage of the module.

The nominal output voltage of the module can be adjusted with a minimum step size of 0.4% over a ±25% range from nominal using the VOUT_TRIM command over the PMBus.

The VOUT_TRIM command is used to apply a fixed offset voltage to the output voltage command value using the "Linear" mode with the exponent fixed at –10 (decimal). The value of the offset voltage is given by

$$V_{OUT(offset)} = VOUT\_TRIM \times 2^{-10}$$

This offset voltage is added to the voltage set through the divider ratio and nominal VREF to produce the trimmed output voltage. The valid range in two's complement for this command is –4000h to 3fffh. The high order two bits of the high byte must both be either 0 or 1. If a value outside of the +/-25% adjustment range is given with this command, the module will set its output voltage to the nominal value (as if VOUT_TRIM had been set to 0), assert SMBALRT#, set the CML bit in STATUS_BYTE and the invalid data bit in STATUS_CML.

Output Voltage Margining Using the PMBus

The module can also have its output voltage margined via PMBus commands. The command VOUT_MARGIN_HIGH sets the margin high voltage, while the command VOUT_MARGIN_LOW sets the margin low voltage. Both the VOUT_MARGIN_HIGH and VOUT_MARGIN_LOW commands use the "Linear" mode with the exponent fixed at –10 (decimal). Two bytes are used for the mantissa with the upper bit [7] of the high byte fixed at 0. The actual margined output voltage is a combination of the VOUT_MARGIN_HIGH or VOUT_MARGIN_LOW and the VOUT_TRIM values as shown below.

MDT040_DS   Rev. 1.9

Digital Feature Descriptions (continued)

Output Voltage Margining Using the PMBus (continued)

$V_{OUT(MH)} = (VOUT\_MARGIN\_HIGH + VOUT\_TRIM) \times 2^{-10}$

$V_{OUT(ML)} = (VOUT\_MARGIN\_LOW + VOUT\_TRIM) \times 2^{-10}$

Note that the sum of the margin and trim voltages cannot be outside the ±25% window around the nominal output voltage. The data associated with VOUT_MARGIN_HIGH and VOUT_MARGIN_LOW can be stored to non-volatile memory using the STORE_DEFAULT_ALL command.

The module is commanded to go to the margined high or low voltages using the OPERATION command. Bits [5:2] are used to enable margining as follows:

00XX : Margin Off

0101 : Margin Low (Ignore Fault)

0110 : Margin Low (Act on Fault)

1001 : Margin High (Ignore Fault)

1010 : Margin High (Act on Fault)

PMBus Adjustable Overcurrent Warning

The module can provide an overcurrent warning via the PMBus. The threshold for the overcurrent warning can be set using the parameter IOUT_OC_WARN_LIMIT. This command uses the "Linear" data format with a two byte data word where the upper five bits [7:3] of the high byte represent the exponent and the remaining three bits of the high byte [2:0] and the eight bits in the low byte represent the mantissa. The exponent is fixed at –1 (decimal). The upper five bits of the mantissa are fixed at 0 while the lower six bits are programmable with a default value of 55.5A (decimal). For production codes after April 2013, the value for IOUT_OC_WARN_LIMIT will be fixed at 57A. For earlier production codes the actual value for IOUT_OC_WARN_LIMIT will vary from module to module due to calibration during production testing. The resolution of this warning limit is 500mA. The value of the IOUT_OC_WARN_LIMIT can be stored to non-volatile memory using the STORE_DEFAULT_ALL command.

Temperature Status via PMBus

The module can provide information related to temperature of the module through the STATUS_TEMPERATURE command. The command returns information about whether the pre-set over temperature fault threshold and/or the warning threshold have been exceeded.

PMBus Adjustable Output Over and Under Voltage Protection

The module has output over and under voltage protection capability. The PMBus command VOUT_OV_FAULT_LIMIT is used to set the output over voltage threshold from four possible values: 108%, 110%, 112% or 115% of the commanded output voltage. The command VOUT_UV_FAULT_LIMIT sets the threshold that causes an output under voltage fault and can also be selected from four possible values: 92%, 90%, 88% or 85%. The default values are 112% and 88% of commanded output voltage. Both commands use two data bytes formatted as two's complement binary integers. The "Linear" mode is used with the exponent fixed to –10 (decimal) and the effective over or under voltage trip points given by:

$V_{OUT(OV\_REQ)} = (VOUT\_OV\_FAULT\_LIMIT) \times 2^{-10}$

$V_{OUT(UV\_REQ)} = (VOUT\_UV\_FAULT\_LIMIT) \times 2^{-10}$

Values within the supported range for over and undervoltage detection thresholds will be set to the nearest fixed percentage. Note that the correct value for VOUT_SCALE_LOOP must be set in the module for the correct over or under voltage trip points to be calculated.

In addition to adjustable output voltage protection, the 40A Digital Mega DLynx™ module can also be programmed for the response to the fault. The VOUT_OV_FAULT RESPONSE and VOUT_UV_FAULT_RESPONSE commands specify the response to the fault. Both these commands use a single data byte with the possible options as shown below.

1. Continue operation without interruption (Bits [7:6] = 00, Bits [5:3] = xxx)

2. Continue for four switching cycles and then shut down if the fault is still present, followed by no restart or continuous restart (Bits [7:6] = 01, Bits [5:3] = 000 means no restart, Bits [5:3] = 111 means continuous restart)

3. Immediate shut down followed by no restart or continuous restart (Bits [7:6] = 10, Bits [5:3] = 000 means no restart, Bits [5:3] = 111 means continuous restart).

MDT040_DS

Rev. 1.9

Digital Feature Descriptions (continued)

PMBus Adjustable Output Over and Under Voltage Protection (continued)

4. Module output is disabled when the fault is present and the output is enabled when the fault no longer exists (Bits [7:6] = 11, Bits [5:3] = xxx).

Note that separate response choices are possible for output over voltage or under voltage faults.

PMBus Adjustable Input Undervoltage Lockout

The module allows adjustment of the input under voltage lockout and hysteresis. The command VIN_ON allows setting the input voltage turn on threshold, while the VIN_OFF command sets the input voltage turn off threshold. For the VIN_ON command, possible values are 3.5 to 14V in 0.5V steps. For the VIN_OFF command, possible values are 3V to 14V in 0.5V steps. If other values are entered for either command, they will be mapped to the closest of the allowed values.

Both the VIN_ON and VIN_OFF commands use the "Linear" format with two data bytes. The upper five bits represent the exponent (fixed at -2) and the remaining 11 bits represent the mantissa. For the mantissa, the four most significant bits are fixed at 0.

Power Good

The module provides a Power Good (PGOOD) signal that is implemented with an open-drain output to indicate that the output voltage is within the regulation limits of the power module. The PGOOD signal will be de-asserted to a low state if any condition such as overtemperature, overcurrent or loss of regulation occurs that would result in the output voltage going outside the specified thresholds. The PGOOD thresholds are user selectable via the PMBus (the default values are as shown in the Feature Specifications Section). Each threshold is set up symmetrically above and below the nominal value. The POWER_GOOD_ON command sets the output voltage level above which PGOOD is asserted (lower threshold). For example, with a 1.2V nominal output voltage, the POWER_GOOD_ON threshold can set the lower threshold to 1.14 or 1.1V. Doing this will automatically set the upper thresholds to 1.26 or 1.3V.

The POWER_GOOD_OFF command sets the level below which the PGOOD command is de-asserted. This command also sets two thresholds symmetrically placed around the nominal output voltage. Normally, the POWER_GOOD_ON threshold is set higher than the POWER_GOOD_OFF threshold.

Both POWER_GOOD_ON and POWER_GOOD_OFF commands use the "Linear" format with the exponent fixed at –10 (decimal). The two thresholds are given by

$$V_{OUT(PGOOD\_ON)} = (POWER\_GOOD\_ON) \times 2^{-10}$$

$$V_{OUT(PGOOD\_OFF)} = (POWER\_GOOD\_OFF) \times 2^{-10}$$

Both commands use two data bytes with bit [7] of the high byte fixed at 0, while the remaining bits are r/w and used to set the mantissa using two's complement representation. Both commands also use the VOUT_SCALE_LOOP parameter so it must be set correctly. The default value of POWER_GOOD_ON is set at 1.1035V and that of the POWER_GOOD_OFF is set at 1.08V. The values associated with these commands can be stored in non-volatile memory using the STORE_DEFAULT_ALL command.

The PGOOD terminal can be connected through a pullup resistor (suggested value 100KΩ) to a source of 5V$_{DC}$ or lower.

Measurement of Output Current, Output Voltage and Input Voltage

The module is capable of measuring key module parameters such as output current and voltage and input voltage and providing this information through the PMBus interface. Roughly every 200μs, the module makes 16 measurements each of output current, voltage and input voltage. Average values of these 16 measurements are then calculated and placed in the appropriate registers. The values in the registers can then be read using the PMBus interface.

Measuring Output Current Using the PMBus

The module measures current by using the inductor winding resistance as a current sense element. The inductor winding resistance is then the current gain factor used to scale the measured voltage into a current reading. This gain factor is the argument of the IOUT_CAL_GAIN command, and consists of two bytes in the linear data format. The exponent uses the upper five bits [7:3] of the high data byte in two-s complement format and is fixed at –15 (decimal). The remaining 11 bits in two's complement binary format represent the mantissa. During manufacture, each module is calibrated by measuring and storing the current gain factor into non-volatile storage.

MDT040_DS   Rev. 1.9

Digital Feature Descriptions (continued)

Measuring Output Current Using the PMBus (continued)

The current measurement accuracy is also improved by each module being calibrated during manufacture with the offset in the current reading. The IOUT_CAL_OFFSET command is used to store and read the current offset. The argument for this command consists of two bytes composed of a 5-bit exponent (fixed at -4d) and a 11-bit mantissa. This command has a resolution of 62.5mA and a range of -4000mA to +3937.5mA.

The READ_IOUT command provides module average output current information. This command only supports positive or current sourced from the module. If the converter is sinking current a reading of 0 is provided. The READ_IOUT command returns two bytes of data in the linear data format. The exponent uses the upper five bits [7:3] of the high data byte in two-s complement format and is fixed at – 4 (decimal). The remaining 11 bits in two's complement binary format represent the mantissa with the 11th bit fixed at 0 since only positive numbers are considered valid.

Note that the current reading provided by the module is not corrected for temperature. The temperature corrected current reading for module temperature T_{Module} can be estimated using the following equation

$$I_{OUT,CORR} = \frac{I_{READ\_OUT}}{1+[(T_{IND} - 30) \times 0.00393]}$$

where I_{OUT_CORR} is the temperature corrected value of the current measurement, I_{READ_OUT} is the module current measurement value, TIND is the temperature of the inductor winding on the module. Since it may be difficult to measure T_{IND}, it may be approximated by an estimate of the module temperature.

Measuring Output Voltage Using the PMBus

The module can provide output voltage information using the READ_VOUT command. The command returns two bytes of data all representing the mantissa while the exponent is fixed at -10 (decimal).

During manufacture of the module, offset and gain correction values are written into the non-volatile memory of the module. The command VOUT_CAL_OFFSET can be used to read and/or write the offset (two bytes consisting of a 16-bit mantissa in two's complement format) while the exponent is always fixed at -10 (decimal). The allowed range for this offset correction is -125 to 124mV. The command VOUT_CAL_GAIN can be used to read and/or write the gain correction - two bytes consisting of a five-bit exponent (fixed at -8) and a 11-bit mantissa. The range of this correction factor is -0.125 to +0.121, with a resolution of 0.004. The corrected output voltage reading is then given by:

V_{OUT}(Final) = [V_{OUT}(Initial) x (1 + VOUT_CAL_GAIN)] + VOUT_CAL_OFFSET

Measuring Input Voltage Using the PMBus

The module can provide output voltage information using the READ_VIN command. The command returns two bytes of data in the linear format. The upper five bits [7:3] of the high data form the two's complement representation of the exponent which is fixed at –5 (decimal). The remaining 11 bits are used for two's complement representation of the mantissa, with the 11th bit fixed at zero since only positive numbers are valid.

During module manufacture, offset and gain correction values are written into the non-volatile memory of the module. The command VIN_CAL_OFFSET can be used to read and/or write the offset - two bytes consisting of a five-bit exponent (fixed at -5) and a11-bit mantissa in two's complement format. The allowed range for this offset correction is -2to 1.968V, and the resolution is 32mV. The command VIN_CAL_GAIN can be used to read and/or write the gain correction - two bytes consisting of a five-bit exponent (fixed at -8) and a 11-bit mantissa. The range of this correction factor is -0.125 to +0.121, with a resolution of 0.004. The corrected output voltage reading is then given by:

V_{IN}(Final) = [V_{IN}(Initial) x (1 + VIN_CAL_GAIN)] + VIN_CAL_OFFSET

Reading the Status of the Module using the PMBus

The module supports a number of status information commands implemented in PMBus. However, not all features are supported in these commands. A 1 in the bit position indicates the fault that is flagged.

MDT040_DS   Rev. 1.9

Technical Specifications (continued)

Digital Feature Descriptions (continued)

Measuring Input Voltage Using the PMBus (continued)

STATUS_BYTE : Returns one byte of information with a summary of the most critical device faults.

Bit Position	Flag	Default Value
7	X	0
6	OFF	0
5	V_{OUT} Overvoltage	0
4	I_{OUT} Overcurrent	0
3	V_{IN} Undervoltage	0
2	Temperature	0
1	CML (Comm. Memory Fault)	0
0	None of the above	0

STATUS_WORD: Returns two bytes of information with a summary of the module's fault/warning conditions.

Bit Position	Flag	Default Value
7	X	0
6	OFF	0
5	V_{OUT} Overvoltage	0
4	I_{OUT} Overcurrent	0
3	V_{IN} Undervoltage	0
2	Temperature	0
1	CML (Comm. Memory Fault)	0
0	None of the above	0

Low Byte

Bit Position	Flag	Default Value
7	V_{OUT} fault or warning	0
6	I_{OUT} fault for warning	0
5	X	0
4	X	0
3	Power_GOOD# (is negated)	0
2	X	0
1	X	0
0	X	0

High Byte

STATUS_VOUT : Returns one byte of information relating to the status of the module's output voltage related faults.

Bit Position	Flag	Default Value
7	V_{OUT} OV Fault	0
6	X	0
5	X	0
4	V_{OUT} UV Fault	0
3	X	0
2	X	0
1	X	0
0	X	0

STATUS_IOUT : Returns one byte of information relating to the status of the module's output voltage related faults.

Bit Position	Flag	Default Value
7	I_{OUT} OC Fault	0
6	X	0
5	I_{OUT} OC Warning	0
4	X	0
3	X	0
2	X	0
1	X	0
0	X	0

STATUS_TEMPERATURE : Returns one byte of information relating to the status of the module's temperature related faults.

Bit Position	Flag	Default Value
7	OT Fault	0
6	OT Warning	0
5	X	0
4	X	0
3	X	0
2	X	0
1	X	0
0	X	0

STATUS_CML : Returns one byte of information relating to the status of the module's communication related faults.

Bit Position	Flag	Default Value
7	Invalid/Unsupported	0
6	Invalid/Unsupported	0
5	Packet Error Check Failed	0
4	X	0
3	X	0
2	X	0
1	Other Communication Fault	0
0	X	0

MDT040_DS   Rev. 1.9

Technical Specifications (continued)

Digital Feature Descriptions (continued)

Measuring Input Voltage Using the PMBus (continued)

MFR_VIN_MIN : Returns minimum input voltage as two data bytes of information in Linear format (upper five bits are exponent – fixed at -2, and lower 11 bits are mantissa in two's complement format – fixed at 12)

MFR_VOUT_MIN : Returns minimum output voltage as two data bytes of information in Linear format (upper five bits are exponent – fixed at -10, and lower 11 bits are mantissa in two's complement format – fixed at 614)

MFR_SPECIFIC_00: Returns information related to the type of module. Bits [7:2] in the Low Byte indicate the module type (000010 corresponds to the UDT020 series of module). Bits 1:0 in the High Byte are used to indicate the manufacturer ID, with 00 reserved for OmniOn.

Bit Position	Flag	Default Value
7:2	Module Name	000010
1:0	Reserved	10

Low Byte

Bit Position	Flag	Default Value
7:0	Module Revision Number	None
1:0	Reserved	00

High Byte

　　　　MDT040_DS　　　　Rev. 1.9

Technical Specifications (continued)

Summary of Supported PMBus Commands

Hex Code	Command	Brief Description	Non-Volatile Memory Storage
01	OPERATION	Turn Module on or off. Also used to margin the output voltage **Format: Unsigned Binary** Bit Position: 7, 6, 5, 4, 3, 2, 1, 0 Access: r/w, r, r/w, r/w, r/w, r/w, r, r Function: On, X, Margin (bits 5-2), X, X Default Value: 0, 0, 0, 0, 0, 0, X, X	
02	ON_OFF_CONFIG	Configures the ON/OFF functionality as a combination of analog ON/OFF pin and PMBus commands **Format: Unsigned Binary** Bit Position: 7, 6, 5, 4, 3, 2, 1, 0 Access: r, r, r, r/w, r/w, r/w, r/w, r Function: X, X, X, pu, cmd, cpr, pol, cpa Default Value: 0, 0, 0, 1, 0, 1, 1, 1	YES
03	CLEAR_FAULTS	Clear any fault bits that may have been set, also releases the SMBALERT# signal if the device has been asserting it.	
10	WRITE_PROTECT	Used to control writing to the module via PMBus. Copies the current register setting in the module whose command code matches the value in the data byte into non-volatile memory (EEPROM) on the module **Format: Unsigned Binary** Bit Position: 7, 6, 5, 4, 3, 2, 1, 0 Access: r/w, r/w, r/w, X, X, X, X, X Function: bit7, bit6, bit5, X, X, X, X, X Default Value: 0, 0, 0, X, X, X, X, X Bit 5: 0 – Enables all writes as permitted in bit6 or bit7 1 – Disables all writes except the WRITE_PROTECT, PAGE OPERATION and ON_OFF_CONFIG (bit 6 and bit7 must be 0) Bit 6: 0 – Enables all writes as permitted in bit5 or bit7 1 – Disables all writes except for the WRITE_PROTECT, PAGE and OPERATION commands (bit5 and bit7 must be 0) Bit 7: 0 – Enables all writes as permitted in bit5 or bit6 1 – Disables all writes except for the WRITE_PROTECT command (bit5 and bit6 must be 0)	YES
11	STORE_DEFAULT_ALL	Copies all current register settings in the module into non-volatile memory (EEPROM) on the module. Takes about 50ms for the command to execute.	
12	RESTORE_DEFAULT_ALL	Restores all current register settings in the module from values in the module non-volatile memory (EEPROM)	
13	STORE_DEFAULT_CODE	Copies the current register setting in the module whose command code matches the value in the data byte into non-volatile memory (EEPROM) on the module Bit Position: 7, 6, 5, 4, 3, 2, 1, 0 Access: W, W, W, W, W, W, W, w Function: Command code	
14	RESTORE_DEFAULT_CODE	Restores the current register setting in the module whose command code matches the value in the data byte from the value in the module non-volatile memory (EEPROM) Bit Position: 7, 6, 5, 4, 3, 2, 1, 0 Access: W, W, W, W, W, W, W, w Function: Command code	

Table 6

MDT040_DS   Rev. 1.9

Technical Specifications (continued)

Summary of Supported PMBus Commands (continued)

Hex Code	Command	Brief Description									Non-Volatile Memory Storage
20	VOUT_MODE	The module has MODE set to Linear and Exponent set to -10. These values cannot be changed									
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r	r	r	r	r	r	r	
		Function	Mode			Exponent					
		Default Value	0	0	0	1	0	1	1	0	
22	VOUT_TRIM	Apply a fixed offset voltage to the output voltage command value. Exponent is fixed at -10.									YES
		Format	**Linear, two's complement binary**								
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r/w	r	r/w	r/w	r/w	r/w	r/w	r/w	
		Function	High Byte								
		Default Value	0	0	0	0	0	0	0	0	
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	
		Function	Low Byte								
		Default Value	0	0	0	0	0	0	0	0	
25	VOUT_MARGIN_HIGH	Sets the target voltage for margining the output high. Exponent is fixed at -10.									YES
		Format	**Linear, two's complement binary**								
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r/w	r/w	r/w	r/w	r/w	r/w	r/w	
		Function	High Byte								
		Default Value	0	0	0	0	0	1	0	1	
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	
		Function	Low Byte								
		Default Value	0	1	0	0	0	1	1	1	
26	VOUT_MARGIN_LOW	Sets the target voltage for margining the output low. Exponent is fixed at -10									YES
		Format	**Linear, two's complement binary**								
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r/w	r/w	r/w	r/w	r/w	r/w	r/w	
		Function	High Byte								
		Default Value	0	0	0	0	0	1	0	0	
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	
		Function	Low Byte								
		Default Value	0	1	0	1	0	0	0	1	
29	VOUT_SCALE_LOOP	Sets the scaling of the output voltage – equal to the feedback resistor divider ratio									YES
		Format	**Linear, two's complement binary**								
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r	r	r	r	r	r/w	r/w	
		Function	Exponent						Mantissa		
		Default Value	1	0	1	1	1	0	0	1	
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	
		Function	Mantissa								
		Default Value	0	0	0	0	0	0	0	0	

Table 6 (continued)

Summary of Supported PMBus Commands (continued)

Hex Code	Command	Brief Description									Non-Volatile Memory Storage
35	VIN_ON	Sets the value of input voltage at which the module turns on									YES
		Format	**Linear, two's complement binary**								
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r	r	r	r	r	r	r	
		Function	Exponent					Mantissa			
		Default Value	1	1	1	1	0	0	0	0	
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r/w	r/w	r/w	r/w	r/w	r/w	r/w	
		Function	Mantissa								
		Default Value	0	0	0	0	1	1	1	0	
36	VIN_OFF	Sets the value of input voltage at which the module turns off									YES
		Format	**Linear, two's complement binary**								
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r	r	r	r	r	r	r	
		Function	Exponent					Mantissa			
		Default Value	1	1	1	1	0	0	0	0	
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r/w	r/w	r/w	r/w	r/w	r/w	r/w	
		Function	Mantissa								
		Default Value	0	0	0	0	1	1	0	0	
38	IOUT_CAL_GAIN	Returns the value of the gain correction term used to correct the measured output current									YES
		Format	**Linear, two's complement binary**								
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r	r	r	r	r	r	r/w	
		Function	Exponent					Mantissa			
		Default Value	1	0	0	0	1	0	0	0	
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	
		Function	Mantissa								
		Default Value	V: Variable based on factory calibration								
39	IOUT_CAL_OFFSET	Returns the value of the offset correction term used to correct the measured output current									
		Format	**Linear, two's complement binary**								
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r	r	r	r	r/w	r	r	
		Function	Exponent					Mantissa			
		Default Value	1	1	1	0	0	1	1	1	
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r	r/w	r/w	r/w	r/w	r/w	r/w	
		Function	Mantissa								
		Default Value	V: Variable based on factory calibration								

Table 6 (continued)

MDT040_DS   Rev. 1.9

Summary of Supported PMBus Commands (continued)

Hex Code	Command	Brief Description									Non-Volatile Memory Storage
40	VOUT_OV_FAULT_LIMIT	Sets the voltage level for an output overvoltage fault. Exponent is fixed at -10. Suggested value shown for 1.2V$_o$. Should be changed for different output voltage. Values can be 108%, 110%, 112% or 115% of output voltage									YES

Format	Linear, two's complement binary							
Bit Position	7	6	5	4	3	2	1	0
Access	r	r/w	r/w	r/w	r/w	r/w	r/w	r/w
Function	High Byte							
Default Value	0	0	0	0	0	1	0	1
Bit Position	7	6	5	4	3	2	1	0
Access	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w
Function	Low Byte							
Default Value	0	1	1	0	0	0	0	0

Hex Code	Command	Brief Description	Non-Volatile Memory Storage
41	VOUT_OV_FAULT_RESPONSE	Instructs the module on what action to take in response to a output overvoltage fault	YES

Format	Unsigned Binary							
Bit Position	7	6	5	4	3	2	1	0
Access	r/w	r/w	r/w	r/w	r/w	r	r	r
Function	RSP[1]	RSP[0]	RS[2]	RS[1]	RS[0]	x	x	x
Default Value	1	1	1	1	1	1	0	0

Hex Code	Command	Brief Description	Non-Volatile Memory Storage
44	VOUT_UV_FAULT_LIMIT	Sets the voltage level for an output undervoltage fault. Exponent is fixed at -10. Suggested value shown for 1.2Vo. Should be changed for different output voltage. Values can be 92%, 90%, 88% or 85% of output voltage	YES

Format	Linear, two's complement binary							
Bit Position	7	6	5	4	3	2	1	0
Access	r	r/w	r/w	r/w	r/w	r/w	r/w	r/w
Function	High Byte							
Default Value	0	0	0	0	0	1	0	0
Bit Position	7	6	5	4	3	2	1	0
Access	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w
Function	Low Byte							
Default Value	0	0	1	1	1	0	0	1

Hex Code	Command	Brief Description	Non-Volatile Memory Storage
45	VOUT_UV_FAULT_RESPONSE	Instructs the module on what action to take in response to a output undervoltage fault	YES

Format	Unsigned Binary							
Bit Position	7	6	5	4	3	2	1	0
Access	r/w	r/w	r/w	r/w	r/w	r	r	r
Function	RSP[1]	RSP[0]	RS[2]	RS[1]	RS[0]	x	x	x
Default Value	0	0	0	0	0	1	0	0

Hex Code	Command	Brief Description	Non-Volatile Memory Storage
46	IOUT_OC_FAULT_LIMIT	Sets the output overcurrent fault level in A (cannot be changed)	YES

Format	Linear, two's complement binary							
Bit Position	7	6	5	4	3	2	1	0
Access	r	r	r	r	r	r	r	r
Function	Exponent					Mantissa		
Default Value	1	1	1	1	1	0	0	0
Bit Position	7	6	5	4	3	2	1	0
Access	r	r	r	r	r	r	r	r
Function	Mantissa							
Default Value	0	1	1	1	0	1	0	0

Table 6 (continued)

MDT040_DS
Rev. 1.9

Summary of Supported PMBus Commands (continued)

Hex Code	Command	Brief Description									Non-Volatile Memory Storage
4A	IOUT_OC_WARN_LIMIT	Sets the output overcurrent warning level in A									YES
		Format	**Linear, two's complement binary**								
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r	r	r	r	r	r	r	
		Function	Exponent					Mantissa			
		Default Value	1	1	1	1	1	0	0	0	
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r	r/w	r/w	r/w	r/w	r/w	r/w	
		Function	Mantissa								
		Default Value	0	1	1	1	0	0	1	0	
5E	POWER_GOOD_ON	Sets the output voltage level at which the PGOOD pin is asserted high. Exponent is fixed at -10.									YES
		Format	**Linear, two's complement binary**								
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r/w	r/w	r/w	r/w	r/w	r/w	r/w	
		Function	High Byte								
		Default Value	0	0	0	0	0	1	0	0	
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	
		Function	Low Byte								
		Default Value	0	1	1	0	1	0	1	0	
5F	POWER_GOOD_OFF	Sets the output voltage level at which the PGOOD pin is de-asserted low. Exponent is fixed at -10.									YES
		Format	**Linear, two's complement binary**								
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r/w	r/w	r/w	r/w	r/w	r/w	r/w	
		Function	High Byte								
		Default Value	0	0	0	0	0	1	0	0	
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	
		Function	Low Byte								
		Default Value	0	1	0	1	0	0	1	0	
61	TON_RISE	Sets the rise time of the output voltage during startup									YES
		Format	**Linear, two's complement binary**								
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r	r	r	r	r	r	r/w	
		Function	Exponent					Mantissa			
		Default Value	1	1	1	0	0	0	0	0	
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	
		Function	Mantissa								
		Default Value	0	0	1	0	1	0	1	1	
78	STATUS_BYTE	Returns one byte of information with a summary of the most critical module faults									
		Format	**Unsigned Binary**								
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r	r	r	r	r	r	r	
		Flag	X	OFF	V_{OUT_OV}	I_{OUT_OC}	V_{IN_UV}	TEMP	CML	OTHER	
		Default Value	0	0	0	0	0	0	0	0	

Table 6 (continued)

     MDT040_DS   Rev. 1.9

Technical Specifications (continued)

Summary of Supported PMBus Commands (continued)

Hex Code	Command	Brief Description	Non-Volatile Memory Storage
79	STATUS_WORD	Returns two bytes of information with a summary of the module's fault/warning conditions	
7A	STATUS_VOUT	Returns one byte of information with the status of the module's output voltage related faults	
7B	STATUS_IOUT	Returns one byte of information with the status of the module's output current related faults	
7D	STATUS_TEMPERATURE	Returns one byte of information with the status of the module's temperature related faults	
7E	STATUS_CML	Returns one byte of information with the status of the module's communication related faults	

79 — STATUS_WORD

Format	Unsigned Binary							
Bit Position	7	6	5	4	3	2	1	0
Access	r	r	r	r	r	r	r	r
Function	V_{OUT}	I_{OUT_OC}	X	X	PGOOD	X	X	X
Default Value	0	0	0	0	0	0	0	0
Bit Position	7	6	5	4	3	2	1	0
Access	r	r	r	r	r	r	r	r
Flag	X	OFF	V_{OUT_OV}	I_{OUT_OC}	V_{IN_UV}	TEMP	CML	OTHER
Default Value	0	0	0	0	0	0	0	0

7A — STATUS_VOUT

Format	Unsigned Binary							
Bit Position	7	6	5	4	3	2	1	0
Access	r	r	r	r	r	r	r	r
Flag	V_{OUT_OV}	X	X	V_{OUT_UV}	X	X	X	X
Default Value	0	0	0	0	0	0	0	0

7B — STATUS_IOUT

Format	Unsigned Binary							
Bit Position	7	6	5	4	3	2	1	0
Access	r	r	r	r	r	r	r	r
Flag	I_{OUT_OC}	X	$I_{OUT\_OC\_Warn}$	X	X	X	X	X
Default Value	0	0	0	0	0	0	0	0

7D — STATUS_TEMPERATURE

Format	Unsigned Binary							
Bit Position	7	6	5	4	3	2	1	0
Access	r	r	r	r	r	r	r	r
Flag	OT_FAILT	OT_ WARN	X	X	X	X	X	X
Default Value	0	0	0	0	0	0	0	0

7E — STATUS_CML

Format	Unsigned Binary							
Bit Position	7	6	5	4	3	2	1	0
Access	r	r	r	r	r	r	r	r
Flag	Invalid Command	Invalid Data	PEC Fail	X	X	X	Other Comm Fault	X
Default Value	0	0	0	0	0	0	0	0

Table 6 (continued)

MDT040_DS   Rev. 1.9

Summary of Supported PMBus Commands (continued)

Hex Code	Command	Brief Description									Non-Volatile Memory Storage
88	READ_VIN	Returns the value of the input voltage applied to the module									
		Format	**Linear, two's complement binary**								
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r	r	r	r	r	r	r	
		Function	Exponent					Mantissa			
		Default Value	1	1	0	1	1	0	0	0	
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r	r	r	r	r	r	r	
		Function	Mantissa								
		Default Value	0	0	0	0	0	0	0	0	
8B	READ_VOUT	Returns the value of the output voltage of the module. Exponent is fixed at -10.									
		Format	**Linear, two's complement binary**								
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r	r	r	r	r	r	r	
		Function	Mantissa								
		Default Value	0	0	0	0	0	0	0	0	
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r	r	r	r	r	r	r	
		Function	Mantissa								
		Default Value	0	0	0	0	0	0	0	0	
8C	READ_IOUT	Returns the value of the output current of the module									
		Format	**Linear, two's complement binary**								
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r	r	r	r	r	r	r	
		Function	Exponent					Mantissa			
		Default Value	1	1	1	0	0	0	0	0	
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r	r	r	r	r	r	r	
		Function	Mantissa								
		Default Value	0	0	0	0	0	0	0	0	
98	PMBUS_REVISION	Returns one byte indicating the module is compliant to PMBus Spec. 1.1 (read only)									YES
		Format	**Unsigned Binary**								
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r	r	r	r	r	r	r	
		Default Value	0	0	0	1	0	0	0	1	
A0	MFR_VIN_MIN	Returns the minimum input voltage the module is specified to operate at (read only)									YES
		Format	**Linear, two's complement binary**								
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r	r	r	r	r	r	r	
		Function	Exponent					Mantissa			
		Default Value	1	1	1	1	0	0	0	0	
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r	r	r	r	r	r	r	
		Function	Mantissa								
		Default Value	0	0	0	0	1	1	0	0	

Table 6 (continued)

MDT040_DS
Rev. 1.9

Summary of Supported PMBus Commands (continued)

Hex Code	Command	Brief Description									Non-Volatile Memory Storage
A4	MFR_VOUT_MIN	Returns the minimum output voltage possible from the module (read only)									YES
		Format	\multicolumn Linear, two's complement binary								
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r	r	r	r	r	r	r	
		Function	Mantissa								
		Default Value	0	0	0	0	0	0	1	0	
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r	r	r	r	r	r	r	
		Function	Mantissa								
		Default Value	0	1	1	0	0	1	1	0	
D0	MFR_SPECIFIC_00	Returns module name information (read only)									YES
		Format	Linear, two's complement binary								
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r	r	r	r	r	r	r	
		Function	Reserved								
		Default Value	0	0	0	0	0	0	0	0	
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r	r	r	r	r	r	r	
		Function	Module Name					Reserved			
		Default Value	0	0	0	1	0	0	1	0	
D4	VOUT_CAL_OFFSET	Applies an offset to the READ_VOUT command results to calibrate out offset errors in module measurements of the output voltage (between -125mV and +124mV). Exponent is fixed at -10.									YES
		Format	Linear, two's complement binary								
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r/w	r	r	r	r	r	r	r	
		Function	Mantissa								
		Default Value	V	0	0	0	0	0	0	0	
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r/w	r/w	r/w	r/w	r/w	r/w	r/w	
		Function	Mantissa								
		Default Value	V	V	V	V	V	V	V	V	
D5	VOUT_CAL_GAIN	Applies a gain correction to the READ_VOUT command results to calibrate out gain errors in module measurements of the output voltage (between -0.125 and 0.121)									YES
		Format	Linear, two's complement binary								
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r	r	r	r	r/w	r	r	
		Function	Exponent					Mantissa			
		Default Value	1	1	0	0	0	0	0	V	
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r	r	r/w	r/w	r/w	r/w	r/w	
		Function	Mantissa								
		Default Value	V	V	V	V	V	V	V	V	

Table 6 (continued)

MDT040_DS   Rev. 1.9

Technical Specifications (continued)

Summary of Supported PMBus Commands (continued)

Hex Code	Command	Brief Description										Non-Volatile Memory Storage
D6	VIN_CAL_OFFSET	Applies an offset correction to the READ_VIN command results to calibrate out offset errors in module measurements of the input voltage (between -2V and +1.968V)										YES

D6 — VIN_CAL_OFFSET format table:

Format	Linear, two's complement binary							
Bit Position	7	6	5	4	3	2	1	0
Access	r	r	r	r	r	r	r/w	r
Function	Exponent					Mantissa		
Default Value	1	1	0	1	V	0	0	V
Bit Position	7	6	5	4	3	2	1	0
Access	r	r	r/w	r/w	r/w	r/w	r/w	r/w
Function	Mantissa							
Default Value	0	0	V	V	V	V	V	V

Hex Code	Command	Brief Description	Non-Volatile Memory Storage
D7	VIN_CAL_GAIN	Applies a gain correction to the READ_VIN command results to calibrate out gain errors in module measurements of the input voltage (between -0.125 and 0.121)	YES

D7 — VIN_CAL_GAIN format table:

Format	Linear, two's complement binary							
Bit Position	7	6	5	4	3	2	1	0
Access	r	r	r	r	r	r	r/w	r
Function	Exponent					Mantissa		
Default Value	1	1	0	0	V	0	0	V
Bit Position	7	6	5	4	3	2	1	0
Access	r	r	r/w	r/w	r/w	r/w	r/w	r/w
Function	Mantissa							
Default Value	0	0	0	V	V	V	V	V

Table 6

MDT040_DS

Rev. 1.9

Technical Specifications (continued)

Thermal Considerations

Power modules operate in a variety of thermal environments; however, sufficient cooling should always be provided to help ensure reliable operation.

Considerations include ambient temperature, airflow, module power dissipation, and the need for increased reliability. A reduction in the operating temperature of the module will result in an increase in reliability. The thermal data presented here is based on physical measurements taken in a wind tunnel. The test set-up is shown in Figure 30. The preferred airflow direction for the module is in Figure 31.

The thermal reference points, T_{ref} used in the specifications are also shown in Figure 30. For reliable operation the temperatures at these points should not exceed 120°C. The output power of the module should not exceed the rated power of the module ($V_{o,set}$ x $I_{o,max}$).

Please refer to the Application Note "Thermal Characterization Process For Open-Frame Board-Mounted Power Modules" for a detailed discussion of thermal aspects including maximum device temperatures.

Figure 30. Thermal Test Setup.

Figure 31. Preferred airflow direction and location of hotspot of the module (T_{ref}).

MDT040_DS   Rev. 1.9

Technical Specifications (continued)

Shock and Vibration

The ruggedized (-D version) of the modules are designed to withstand elevated levels of shock and vibration to be able to operate in harsh environments. The ruggedized modules have been successfully tested to the following conditions:

Non operating random vibration:

Random vibration tests conducted at 25C, 10 to 2000Hz, for 30 minutes each level, starting from 30Grms (Z axis) and up to 50Grms (Z axis). The units were then subjected to two more tests of 50Grms at 30 minutes each for a total of 90 minutes.

Operating shock to 40G per Mil Std. 810G, Method 516.4 Procedure I:

The modules were tested in opposing directions along each of three orthogonal axes, with waveform and amplitude of the shock impulse characteristics as follows:

All shocks were half sine pulses, 11 milliseconds (ms) in duration in all 3 axes.

Units were tested to the Functional Shock Test of MIL-STD-810, Method 516.4, Procedure I - Figure 516.4-4. A shock magnitude of 40G was utilized. The operational units were subjected to three shocks in each direction along three axes for a total of eighteen shocks.

Operating vibration per Mil Std 810G, Method 514.5 Procedure I:

The ruggedized (-D version) modules are designed and tested to vibration levels as outlined in MIL-STD-810G, Method 514.5, and Procedure 1, using the Power Spectral Density (PSD) profiles as shown in Table 7 and Table 8 for all axes. Full compliance with performance specifications was required during the performance test. No damage was allowed to the module and full compliance to performance specifications was required when the endurance environment was removed. The module was tested per MIL-STD-810, Method 514.5, Procedure I, for functional (performance) and endurance random vibration using the performance and endurance levels shown in Table 7 and Table 8 for all axes. The performance test has been split, with one half accomplished before the endurance test and one half after the endurance test (in each axis). The duration of the performance test was at least 16 minutes total per axis and at least 120 minutes total per axis for the endurance test. The endurance test period was 2 hours minimum per axis.

Frequency (Hz)	PSD Level (G2/Hz)	Frequency (Hz)	PSD Level (G2/Hz)	Frequency (Hz)	PSD Level (G2/Hz)
10	1.14E-03	170	2.54E-03	690	1.03E-03
30	5.96E-03	230	3.70E-03	800	7.29E-03
40	9.53E-04	290	7.99E-04	890	1.00E-03
50	2.08E-03	340	1.12E-02	1070	2.67E-03
90	2.08E-03	370	1.12E-02	1240	1.08E-03
110	7.05E-04	430	8.84E-04	1550	2.54E-03
130	5.00E-03	490	1.54E-03	1780	2.88E-03
140	8.20E-04	560	5.62E-04	2000	5.62E-04

Table 7: Performance Vibration Qualification - All Axes

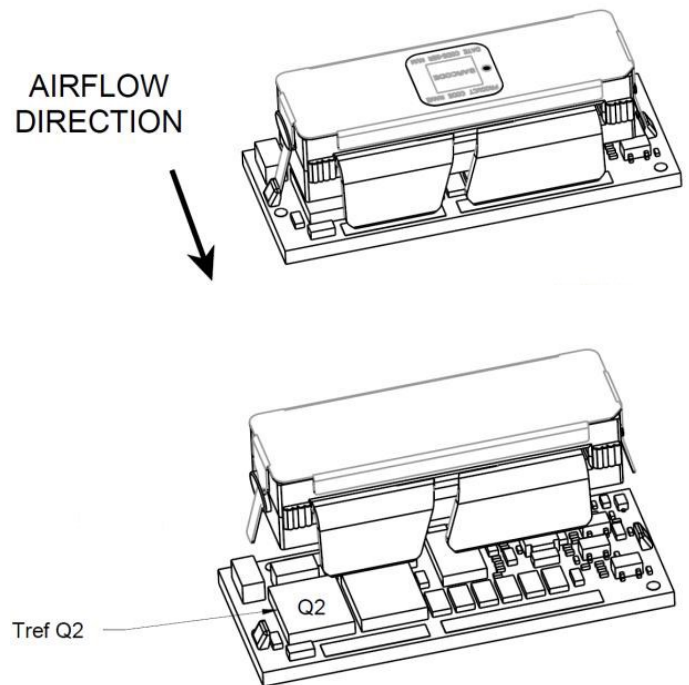| Frequency (Hz)	PSD Level(G2/Hz)	Frequency (Hz)	PSD Level (G2/Hz)	Frequency (Hz)	PSD Level (G2/Hz)
10	0.00803	170	0.01795	690	0.00727
30	0.04216	230	0.02616	800	0.05155
40	0.00674	290	0.00565	890	0.00709
50	0.01468	340	0.07901	1070	0.01887
90	0.01468	370	0.07901	1240	0.00764
110	0.00498	430	0.00625	1550	0.01795
130	0.03536	490	0.01086	1780	0.02035
140	0.0058	560	0.00398	2000	0.00398

Table 8: Endurance Vibration Qualification - All Axes

MDT040_DS   Rev. 1.9

Technical Specifications (continued)

Example Application Circuit

Requirements:

V_{in}:	12V
V_{out}:	1.8V
I_{out}:	30A max., worst case load transient is from 20A to 30A
ΔV_{out}:	1.5% of V_{out} (27mV) for worst case load transient
$V_{in, ripple}$	1.5% of V_{in} (180mV$_{p-p}$)

CI1	Decoupling cap - 1x0.01µF/16V ceramic capacitor (e.g. Murata LLL185R71E103MA01)
CI2	3x22µF/16V ceramic capacitor (e.g. Murata GRM32ER61C226KE20)
CI3	470µF/16V bulk electrolytic
CO1	Decoupling cap - 1x0.01µF/16V ceramic capacitor (e.g. Murata LLL185R71E103MA01)
CO2	4 x 47µF/6.3V ceramic capacitor (e.g. Murata GRM31CR60J476ME19)
CO3	6 X330µF/6.3V Polymer (e.g. Sanyo Poscap)
C_{Tune}	5600pF ceramic capacitor (can be 1206, 0805 or 0603 size)
R_{Tune}	220 ohms SMT resistor (can be 1206, 0805 or 0603 size)
R_{Trim}	10kΩ SMT resistor (can be 1206, 0805 or 0603 size, recommended tolerance of 0.1%)

Note: The DATA, CLK and SMBALRT pins do not have any pull-up resistors inside the module. Typically, the SMBus master controller will have the pull-up resistors as well as provide the driving source for these signals.

MDT040_DS
Rev. 1.9

Mechanical Outline

Dimensions are in millimeters and (inches).

Tolerances: x.x mm ±0.5 mm (x.xx in±0.02 in.) [Unless otherwise indicated]

x.xx mm ± 0.25 mm (x.xxx in ± 0.010 in.)

PIN	FUNCTION	PIN	FUNCTION
1	ON/OFF	11	SIG_GND
2	V_{IN}	12	VS-
3	SEQ	13	CLK
4	GND	14	DATA
5	V_{OUT}	15	SYNC
6	TRIM	16	PG
7	VS+	17	SMBALERT#
8	GND	18	ADDRESS 0
9	SHARE	19	ADDRESS 1
10	GND		

MDT040_DS

Rev. 1.9

Technical Specifications (continued)

Recommended Pad Layout

Dimensions are in millimeters and (inches).

Tolerances: x.x mm ±0.5 mm (x.xx in±0.02 in.) [Unless otherwise indicated]

x.xx mm ± 0.25 mm (x.xxx in ± 0.010 in.)

PIN	FUNCTION	PIN	FUNCTION
1	ON/OFF	11	SIG_GND
2	V_{IN}	12	VS-
3	SEQ	13	CLK
4	GND	14	DATA
5	V_{OUT}	15	SYNC
6	TRIM	16	PG
7	VS+	17	SMBALERT#
8	GND	18	ADDRESS 0
9	SHARE	19	ADDRESS 1
10	GND		

MDT040_DS   Rev. 1.9

Technical Specifications (continued)

Packaging Details

The 12V Digital Mega DLynx™ 40A modules are supplied in tape & reel as standard. Modules are shipped in quantities of 140 modules per reel.

All Dimensions are in millimeters and (in inches).

Reel Dimensions:

Outside Dimensions:	330.2 mm (13.00")
Inside Dimensions:	177.8 mm (7.00")
Tape Width:	56.00 mm (2.205")

MDT040_DS
Rev. 1.9

Technical Specifications (continued)

Surface Mount Information

Pick and Place

The 40A Digital Mega DLynx™ modules use an open frame construction and are designed for a fully automated assembly process. The modules are fitted with a label designed to provide a large surface area for pick and place operations. The label meets all the requirements for surface mount processing, as well as safety standards, and is able to withstand reflow temperatures of up to 300°C. The label also carries product information such as product code, serial number and the location of manufacture.

Nozzle Recommendations

The module weight has been kept to a minimum by using open frame construction. Variables such as nozzle size, tip style, vacuum pressure and placement speed should be considered to optimize this process. The minimum recommended inside nozzle diameter for reliable operation is 3mm. The maximum nozzle outer diameter, which will safely fit within the allowable component spacing, is 7 mm.

Bottom Side / First Side Assembly

This module is not recommended for assembly on the bottom side of a customer board. If such an assembly is attempted, components may fall off the module during the second reflow process.

Lead Free Soldering

The modules are lead-free (Pb-free) and RoHS compliant and fully compatible in a Pb-free soldering process. Failure to observe the instructions below may result in the failure of or cause damage to the modules and can adversely affect long-term reliability.

Pb-free Reflow Profile

Power Systems will comply with J-STD-020 Rev. C (Moisture/Reflow Sensitivity Classification for Nonhermetic Solid State Surface Mount Devices) for both Pb-free solder profiles and MSL classification procedures. This standard provides a recommended forced-air-convection reflow profile based on the volume and thickness of the package (table 4-2). The suggested Pb-free solder paste is Sn/Ag/Cu (SAC). The recommended linear reflow profile using Sn/Ag/Cu solder is shown in Fig. 32. Soldering outside of the recommended profile requires testing to verify results and performance.

MSL Rating

The 40A Digital Mega DLynx™ modules have a MSL rating of 2a.

Storage and Handling

The recommended storage environment and handling procedures for moisture-sensitive surface mount packages is detailed in J-STD-033 Rev. A (Handling, Packing, Shipping and Use of Moisture/Reflow Sensitive Surface Mount Devices). Moisture barrier bags (MBB) with desiccant are required for MSL ratings of 2 or greater. These sealed packages should not be broken until time of use. Once the original package is broken, the floor life of the product at conditions of ≤ 30 °C and 60% relative humidity varies according to the MSL rating (see J-STD-033A). The shelf life for dry packed SMT packages will be a minimum of 12 months from the bag seal date, when stored at the following conditions: < 40 °C, < 90% relative humidity.

Figure 32. Recommended linear reflow profile using Sn/Ag/Cu solder.

Post Solder Cleaning and Drying Considerations

Post solder cleaning is usually the final circuit-board assembly process prior to electrical board testing. The result of inadequate cleaning and drying can affect both the reliability of a power module and the testability of the finished circuit-board assembly. For guidance on appropriate soldering, cleaning and drying procedures, refer to Board Mounted Power Modules: Soldering and Cleaning Application Note (AN04-001).

MDT040_DS Rev. 1.9

Ordering Information

Please contact your OmniOn Sales Representative for pricing, availability and optional features.

Device Codes	Input Voltage Range	Output Voltage	Output Current	On/Off Logic	Sequencing	Ordering Codes
MDT040A0X3-SRPHZ	4.5 – 14.4V$_{dc}$	0.45 – 2.0V$_{dc}$	40A	Negative	Yes	CC109159760
MDT040A0X43-SRPHZ	4.5 – 14.4V$_{dc}$	0.45 – 2.0V$_{dc}$	40A	Positive	Yes	CC109159777
MDT040A0X3-SRPHDZ	4.5 – 14.4V$_{dc}$	0.45 – 2.0V$_{dc}$	40A	Negative	Yes	150022587

Table 7. Device Codes

-Z refers to RoHS compliant parts

Package Identifier	Family	Sequencing Option	Output current	Output voltage	On/Off logic	Remote Sense	Options				ROHS Compliance
U	D	T	040A0	X		3	-SR	-P	-H	-D	Z
P=Pico U=Micro M=Mega G=Giga	D= Dlynx Digital V = DLynx Analog.	T=with EZ Sequence X=without sequencing	40A	X = Programmable output	4 = positive No entry = negative	3 = Remote Sense	S = Surface Mount R = Tape & Reel	Paralleling	2 Extra Ground Pins	D = 105°C operating ambient, 40G operating shock as per MIL Std. 810G,	Z = ROHS6

Table 8. Coding scheme

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Contact Us

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MDT040_DS   Rev. 1.9

Change History (excludes grammar & clarifications)

Revision	Date	Description of the change
1.8	03/23/2022	RoHS, Updated as per template
1.9	11/07/2023	Updated as per OmniOn template

MDT040_DS Rev. 1.9

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MDT040_DS   Rev. 1.9